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TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX540F,TC74LCX540FW,TC74LCX540FT,TC74LCX540FK

Low-Voltage Octal Bus Buffer (inverted) with 5-V Tolerant Inputs and Outputs

The TC74LCX540F/FW/FT/FK is a high-performance CMOS octal bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage $(3.3 \text{ V}) \text{ V}_{CC}$ applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

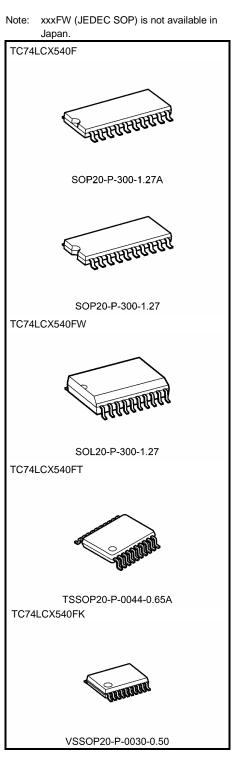
The TC74LCX540F/FW/FT is an inverting 3-state buffer having two active-low output enables. When either $\overline{OE1}$ or $\overline{OE2}$ are high, the terminal outputs are in the high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

Features

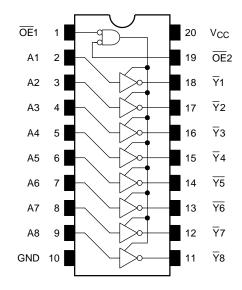
- Low-voltage operation: VCC = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 6.5 \text{ ns} (\text{max}) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (min) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 540 type

| Weight | |
|----------------------|-----------------|
| SOP20-P-300-1.27A | : 0.22 g (typ.) |
| SOP20-P-300-1.27 | : 0.22 g (typ.) |
| SOL20-P-300-1.27 | : 0.46 g (typ.) |
| TSSOP20-P-0044-0.65A | : 0.08 g (typ.) |
| VSSOP20-P-0030-0.50 | : 0.03 g (typ.) |



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Pin Assignment (top view)



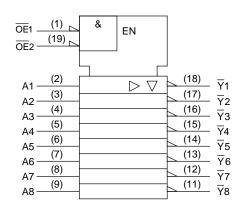
Truth Table

| | Inputs | | Outputs |
|-----|--------|----|---------|
| OE1 | OE2 | An | Outputs |
| н | Х | Х | Z |
| Х | Н | Х | Z |
| L | L | н | L |
| L | L | L | н |

X: Don't care

Z: High impedance

IEC Logic Symbol



Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|------------------------------------|-----------------------------------|-------------------------------|------|
| Power supply voltage | V _{CC} | -0.5 to 7.0 | V |
| DC input voltage | V _{IN} | -0.5 to 7.0 | V |
| | | -0.5 to 7.0 (Note 2) | |
| DC output voltage | V _{OUT} | -0.5 to V _{CC} + 0.5 | V |
| | | (Note 3) | |
| Input diode current | I _{IK} | -50 | mA |
| Output diode current | I _{OK} | ±50 (Note 4) | mA |
| DC output current | IOUT | ±50 | mA |
| Power dissipation | PD | 180 | mW |
| DC V _{CC} /ground current | I _{CC} /I _{GND} | ±100 | mA |
| Storage temperature | T _{stg} | –65 to 150 | °C |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in OFF state

- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: $V_{OUT} < GND, V_{OUT} > VCC$

Recommended Operating Conditions (Note 1)

| Characteristics | Symbol | Rating | Unit | |
|--------------------------|------------------|-------------------------------|------|--|
| Power supply voltage | V _{CC} | 2.0 to 3.6 | V | |
| rower supply voltage | V CC | 1.5 to 3.6 (Note 2) | v | |
| Input voltage | V _{IN} | 0 to 5.5 | V | |
| Output voltage | Vaum | 0 to 5.5 (Note 3) | V | |
| Culput Voltage | Vout | 0 to V _{CC} (Note 4) | v | |
| | lau/lau | ±24 (Note 5) | mA | |
| Output current | IOH/IOL | ±12 (Note 6) | ma | |
| Operating temperature | T _{opr} | -40 to 85 | °C | |
| Input rise and fall time | dt/dv | 0 to 10 (Note 7) | ns/V | |

Note 1: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

- Note 3: Output in OFF state
- Note 4: High or low state
- Note 5: $V_{CC} = 3.0$ to 3.6 V
- Note 6: $V_{CC} = 2.7$ to 3.0 V
- Note 7: $V_{IN} = 0.8 \mbox{ to } 2.0 \mbox{ V}, \mbox{ } V_{CC} = 3.0 \mbox{ V}$

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

| Characte | ristics | Symbol | Test Condition | | | | V _{CC} (V) | Min | Max | Unit |
|---------------------------------|----------------------------------|-----------------|---|---------------------------|------------|--------------------------|---------------------|-----|-----|------|
| la put velte pe | H-level | VIH | - | | 2.7 to 3.6 | 2.0 | _ | V | | |
| Input voltage | L-level | VIL | - | _ | 2.7 to 3.6 | _ | 0.8 | v | | |
| | | | | I _{OH} = -100 μA | 2.7 to 3.6 | V _{CC} - 0.2 | _ | | | |
| | H-level | V _{OH} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | $I_{OH} = -12 \text{ mA}$ | 2.7 | 2.2 | _ | | | |
| | | | | $I_{OH} = -18 \text{ mA}$ | 3.0 | 2.4 | _ | | | |
| Output voltage | | | | $I_{OH} = -24 \text{ mA}$ | 3.0 | 2.2 | _ | V | | |
| | | | | $I_{OL} = 100 \ \mu A$ | 2.7 to 3.6 | _ | 0.2 | | | |
| | L-level | Max | | $I_{OL} = 12 \text{ mA}$ | 2.7 | _ | 0.4 | | | |
| | L-level | V _{OL} | $V_{IN} = V_{IH}$ or V_{IL} | I _{OL} = 16 mA | 3.0 | _ | 0.4 | | | |
| | | | | $I_{OL} = 24 \text{ mA}$ | 3.0 | _ | 0.55 | | | |
| Input leakage curre | nt | I _{IN} | $V_{IN} = 0$ to 5.5 V | - | 2.7 to 3.6 | _ | ±5.0 | μA | | |
| 3-state output off-st | 3-state output off-state current | | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$ | | 2.7 to 3.6 | _ | ±5.0 | μΑ | | |
| Power off leakage of | current | IOFF | $V_{IN}/V_{OUT} = 5.5 V$ | | 0 | _ | 10.0 | μΑ | | |
| | $V_{IN} = V_{CC}$ or GND | | V _{IN} = V _{CC} or GND | | 2.7 to 3.6 | | 10.0 | | | |
| Quiescent supply c | | Icc | $V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$ | | 2.7 to 3.6 | _ | ±10.0 | μA | | |
| Increase in I _{CC} per | input | ΔI_{CC} | $V_{IH} = V_{CC} - 0.6 \text{ V}$ | | 2.7 to 3.6 | | 500 | | | |

AC Characteristics (Ta = -40 to 85°C)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Min | Max | Unit |
|------------------------|-------------------|--------------------|-------------------------------|-----|-----|------|
| Propagation delay time | t _{pLH} | Figure 1, Figure 2 | 2.7 | _ | 7.5 | ns |
| riopagation delay time | t _{pHL} | | $\textbf{3.3}\pm\textbf{0.3}$ | 1.5 | 6.5 | 115 |
| Output enable time | t _{pZL} | Figure 4. Figure 2 | 2.7 | _ | 9.5 | ns |
| | t _{pZH} | Figure 1, Figure 3 | $\textbf{3.3}\pm\textbf{0.3}$ | 1.5 | 8.5 | 115 |
| Output disable time | t _{pLZ} | Figure 1, Figure 3 | 2.7 | _ | 8.5 | ns |
| | t _{pHZ} | | $\textbf{3.3}\pm\textbf{0.3}$ | 1.5 | 7.5 | 115 |
| Output to output skew | t _{osLH} | (Note) | 2.7 | | _ | ns |
| | t _{osHL} | (NOTE) | $\textbf{3.3}\pm\textbf{0.3}$ | | 1.0 | 115 |

Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|--|------------------|--|---------------------|------|------|
| Quiet output maximum dynamic V_{OL} | VOLP | $V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ | 3.3 | 0.8 | V |
| Quiet output minimum dynamic V _{OL} | V _{OLV} | $V_{IH}=3.3~V,~V_{IL}=0~V$ | 3.3 | 0.8 | V |

Capacitive Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|-------------------------------|------------------|------------------------------|---------------------|------|------|
| Input capacitance | C _{IN} | _ | 3.3 | 7 | pF |
| Output capacitance | C _{OUT} | | 3.3 | 8 | pF |
| Power dissipation capacitance | C _{PD} | f _{IN} = 10 MHz (No | e) 3.3 | 40 | pF |

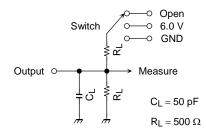
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

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AC Test Circuit



| Parameter | Switch |
|-------------------------------------|--------|
| t _{pLH} , t _{pHL} | Open |
| t _{pLZ} , t _{pZL} | 6.0 V |
| t _{pHZ} , t _{pZH} | GND |



AC Waveform

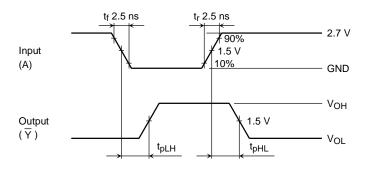


Figure 2 t_{pLH}, t_{pHL}

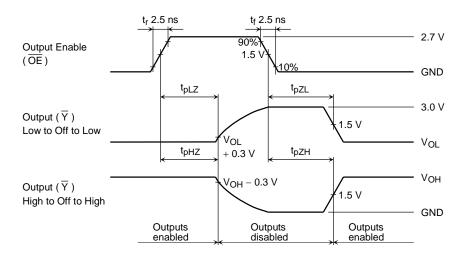
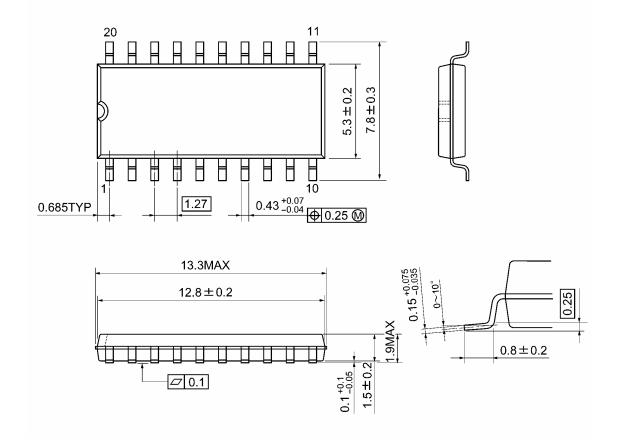


Figure 3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$

Package Dimensions

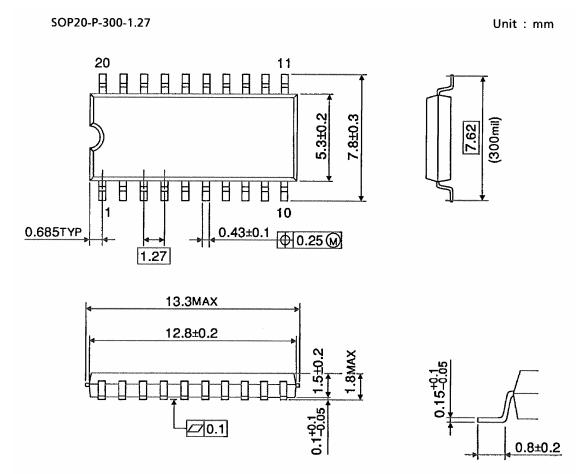
SOP20-P-300-1.27A

Unit: mm



Weight: 0.22 g (typ.)

Package Dimensions

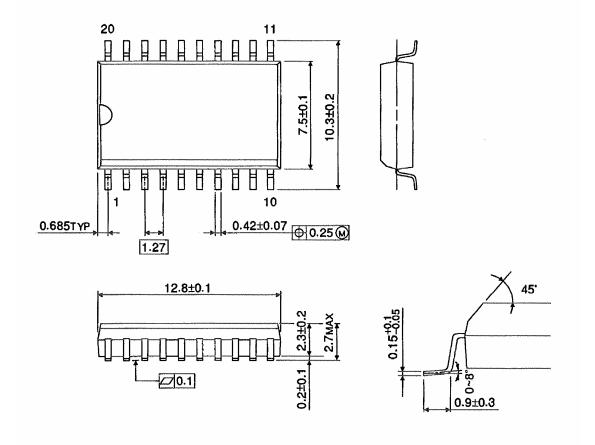


Weight: 0.22 g (typ.)

Package Dimensions (Note)

SOL20-P-300-1.27

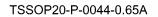
Unit : mm



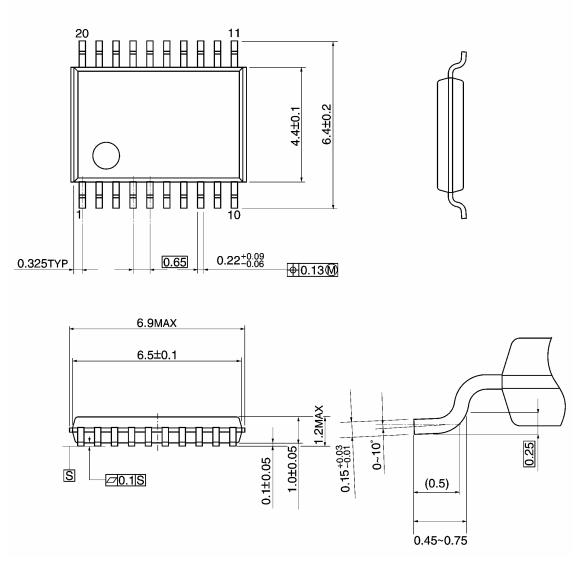
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Package Dimensions



Unit: mm



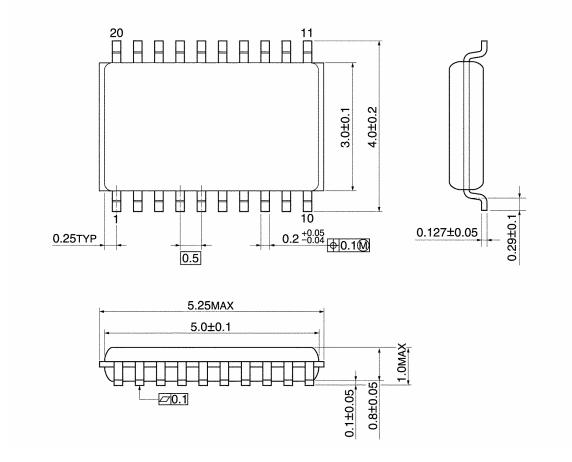
Weight: 0.08 g (typ.)

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Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm



Weight: 0.03 g (typ.)

Note: Lead (Pb)-Free Packages SOP20-P-300-1.27A TSSOP20-P-0044-0.65A VSSOP20-P-0030-0.50

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Handbook" etc. 021023_A

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